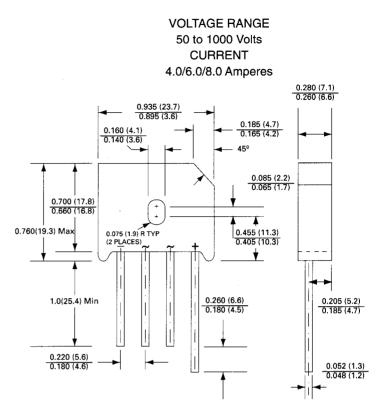
KBU4A ...KBU4M; KBU6A ...KBU6M; KBU8A ...KBU8M 4.0A/6.0A/8.0A SINGLE - PHASE SILICON BRIDGE

Features

- Ideal for printed circuit board
- Reliable low cost construction utilizing molded plastic technique
- Plastic material has Underwriters Laboratory Flammability Classification 94V-0.
- Surge overload rating 200 amperes peak
- Mounting Position: Any
- Mounting Torgue: 5 In. lb. max
- U/L recognized file # 142814



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25 °C ambient temperature unless specified Resistive or inductive load,60 Hz. For capacitive load, derate current by 20%.

	KBU4A	KBU4B	KBU4D	KBU4	G KBU4.	KBU4K	KBU4M	
	KBU6A	KBU6B	KBU6D	KBU6	G KBU6.	KBU6K	KBU6M	
	KBU8A	KBU8B	KBU8D	KBU8	G KBU8.	KBU8K	KBU8M	UNITS
Maximum Recurrent Peak Reverse Voltage	50	100	200	400	600	800	1000	V
Max RMS Bridge Input Voltage	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	50	100	200	400	600	800	1000	V
Maximum Average Forward $T_c = 100 \ ^{\circ}C$ Rectified Output Current at $T_A = 50 \ ^{\circ}C/40 \ ^{\circ}C/45 \ ^{\circ}C$	KBU4	40 40			60 60	KBU8	80 60	A A
Peak Forward Surge Current, 8.3 ms single half sine-wave superimposed on rated load (JEDEC medthod)		200			250		300	Α
Maximum Instantanous Forward Voltage Drop per element at 3.0A/3.0A/8.0A		1.0	— кві		1.0		1.0	V
Maximum Reverse Leakage at rated $T_A = 25 \text{ °C}$ DC Block Voltage per element $T_C = 100 \text{ °C}$		10 100			10 200		10 300	μA mA
Operating and storage temperature Range, TJ,TsTG	-65 to + 150							°C

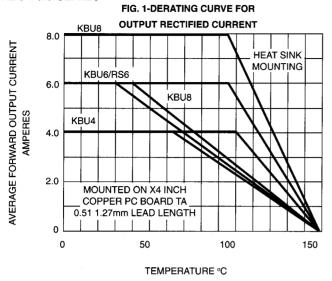


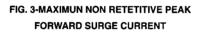
SEMTECH ELECTRONICS LTD. (wholly owned subsidiary of HONEY TECHNOLOGY LTD.)

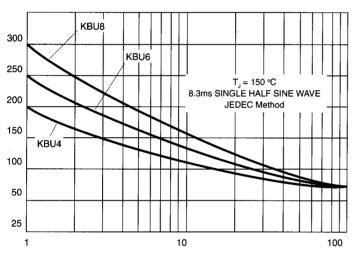


KBU4A ...KBU4M; KBU6A ...KBU6M; KBU8A ...KBU8M 4.0A/6.0A/8.0A SINGLE - PHASE SILICON BRIDGE

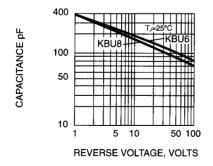
RATING AND CHARACTERISTICS CURVES KBU4/6/8 SERIES

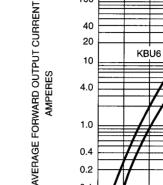






NUMBER OF CYCLES AT 60 Hz

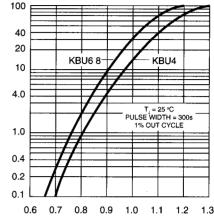




INSTANTANEOUS REVERSE CURRENT, MICROAMPERES

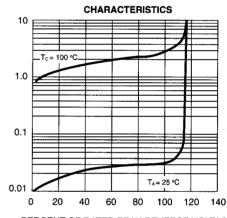
CAPACITANCE pF





INSTANTEOUS FORWARD VOLTAGE, VOLTS

FIG. 4-TYPICAL REVERSE



PERCENT OF RATED PEAK REVERSE VOLTAGE

FIG. 5-TYPICAL JUNCTION CAPACITANCE PER ELEMENT 250 200 квÙ $T_1 = 25$ 150 100 50 0.1 1.0 10 100 **REVERSE VOLTAGE, VOLTS**





SEMTECH ELECTRONICS LTD. (wholly owned subsidiary of HONEY TECHNOLOGY LTD.)

This datasheet has been downloaded from:

www.DatasheetCatalog.com

Datasheets for electronic components.